# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## **OMPOUND FIELD EFFECT POWER TRANSISTOR**



**μPA1603** 

## **MONOLITHIC POWER MOS FET ARRAY**

#### **DESCRIPTION**

The  $\mu$ PA1603 is Monolithic N-channel Power MOS FET Array that built in 4 circuits, Clump Diode and resistances designed for LED, Relay, Thermal Head, and so on.

#### **FEATURES**

- Direct driving is possible by standard Logic IC or Microcomputer.
   (4 V driving is possible)
- Output Voltage: Vo(peak) = 50 V MAX.
   Output Current: Io(peak) = 1.5 A MAX.
- Ron = 1  $\Omega$  TYP. at: lo = 600 mA, Vi = 4 V
- Wide Operation Temperature: -40 to +85 °C
- Output Voltage Clump Diode built in.

#### ORDERING INFORMATION

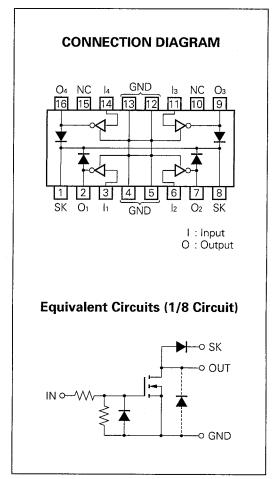
Part Number	Part Number Package	
μPA1603CX	16-Pin DIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Output Voltage	Vo(DC)	30	V
Output Peak Voltage*	VO(peak)	50	V
Input Voltage	Vı	-0.5 to +20	V
Output Current (DC)	lo(DC)	870	mA/unit
Output Current (pulse)**	lo(pulse)	1500	mA/unit
Input Current	lı	±10	mA/unit
Diode Reverse Voltage	VR	50	V
Diode Forward Current	lF	1500	mA/unit
Total Power Dissipation	Po	1.0	W/PKG
Operating Temperature	Topt	-40 to +85	°C
Storage Temperature	$T_{stg}$	-55 to +150	°C

- \* PW ≦ 10 ms, Duty Cycle ≦ 50 %
- \*\* PW ≦ 10 ms, Duty Cycle ≦ 30 %







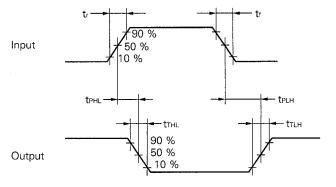
## RECOMMENDED OPERATING CONDITIONS (Ta = -40 to +85 °C)

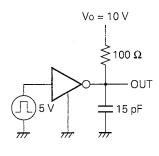
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	Vo(DC)			28	V	
	lo(DC)			540	mA/unit	DC, 1 circuit
Output Current	IO(pulse)			600	mA/unit	PW ≦ 10 ms, Duty Cycle ≦ 20 %, 4 circuits
Input Voltage	Vı	0		15	V	
High-Level Input Voltage	Vін	2			V	
Low-Level Input Voltage	VIL			0.8	V	
Diode Reverse Voltage	Vr			40	V	
Diode Forward Current	İF			600	mA	

## **ELECTRICAL CHARACTERISTICS (Ta = 25 °C)**

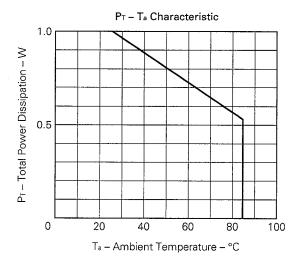
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Output Leakage Current	lo(OFF)			10	μΑ	VI = 0, Vo = 50 V	
Output On-state Resistance	Ron		1	1.3	Ω	V <sub>I</sub> = 4 V, I <sub>O</sub> = 600 mA	
	V0(0N)1		:	0.1	V	Vı = 5 V, lo = 10 mA	
Output On-state Voltage	V0(0N)2			1.0	٧	Vi = 5 V, lo = 600 mA	
	Vi(OFF)			0.8	٧	Vo = 50 V, Io = 100 μA	
Input Voltage	V1(0N)1	2			V	Vo = 0.8 V, lo = 1 mA	
	VI(ON)2	4			٧	Vo = 0.8 V, Io = 600 mA	
Land Committee	Ін			2	mA	VI = 20 V, Vo = 0 V	
Input Current	lıı			-1	μΑ	VI = 0 V, Vo = 50 V	
Input Capacitance	Ciss		80		pF	V <sub>I</sub> = 0 V	
Output Capacitance	Coss		100		pF	Vo = 10 V	
Reverse Transfer Capacitance	Crss		40		рF	f = 1 MHz	
Delay Time	<b>T</b> PHL		20		ns	Vo = 10 V, RL = 100 Ω	
Delay Time	<b>t</b> PLH	•	70		ns	C <sub>L</sub> = 15 pF	
Rise Time	tтьн	-	50		ns	tr, tr ≦ 5 ns See Fig. 1	
Fall Time	tтнь		30		ns		
Diada Lashaus Commun		, ,		50	μΑ	V <sub>R</sub> = 50 V, T <sub>a</sub> = 25 °C	
Diode Leakage Current	l <sub>R</sub>			100	μΑ	V <sub>R</sub> = 50 V, T <sub>a</sub> = 85 °C	
Diode Forward Voltage	VF			2	٧	IF = 1.25 A	

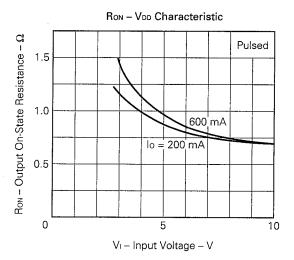
Fig. 1 Switching Wave Forms and Test Circuits

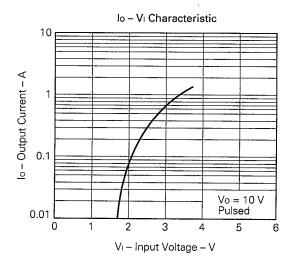


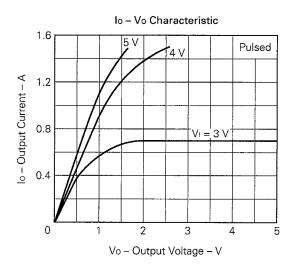


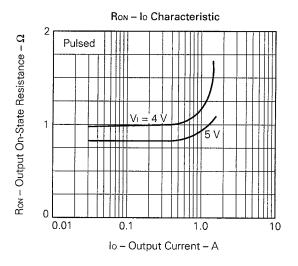
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

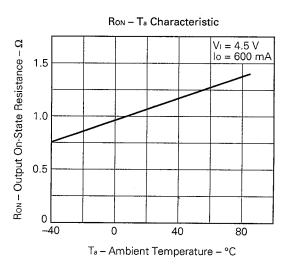


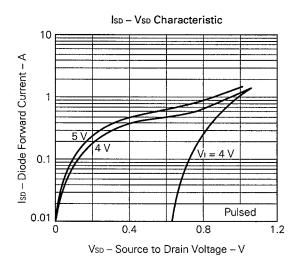


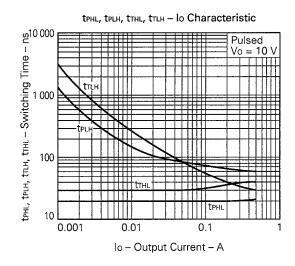










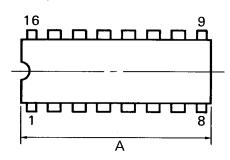


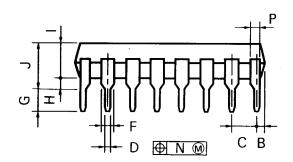


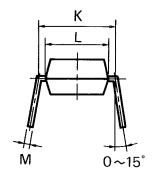
## **PACKAGE DIMENSIONS**

• μPA1603CX

## 16PIN PLASTIC DIP (300 mil)







P16C-100-300A,C

## **NOTES**

- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
Α	20.32 MAX.	0.800 MAX.
В	1.27 MAX.	0.050 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50 <sup>±0.10</sup>	0.020 + 0.004
F	1.2 MIN.	0.047 MIN.
G	3.5 <sup>±0.3</sup>	0.138 ± 0.012
Н	0.51 MIN.	0.020 MIN.
ı	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
К	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
М	0.25 - 0.10	0.010 - 0.004
N	0.25	0.01
Р	1.0 MIN.	0.039 MIN.



### **RECOMMENDED SOLDERING CONDITIONS**

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

### TYPES OF THROUGH HOLE MOUNT DEVICE

### $\mu$ PA1603CX

Soldering process	Soldering conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

### Reference

Document name	Document No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Semiconductor device package manual	IEI-1213
SMD surface mount technology manual	IEI-1207

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